

WEST Search History for Application 10593576

Creation Date: 2008090211:23

Query	DB	Op.	Plur.	Thes.	Date
memory	PGPB, USPT	ADJ	YES		06-02-2008
(memory) and (phase-change or phase change)	PGPB, USPT	ADJ	YES		06-02-2008
(memory and (phase-change or phase change)) and (antenna or electro-magnetic or electromagnetic)	PGPB, USPT	ADJ	YES		06-02-2008
(memory and (phase-change or phase change) and (antenna or electro-magnetic or electromagnetic)) and (power or voltage)	PGPB, USPT	ADJ	YES		06-02-2008
(memory and (phase-change or phase change) and (antenna or electro-magnetic or electromagnetic) and (power or voltage)) and (bitline\$ or bit line\$)	PGPB, USPT	ADJ	YES		06-02-2008
(memory and (phase-change or phase change) and (antenna or electro-magnetic or electromagnetic) and (power or voltage) and (bitline\$ or bit line\$)) and (wordline\$ or word line\$)	PGPB, USPT	ADJ	YES		06-02-2008
(memory and (phase-change or phase change) and (antenna or electro-magnetic or electromagnetic) and (power or voltage) and (bitline\$ or bit line\$)) and (phase-change or phase change) adj2 (layer or film or material)	PGPB, USPT	ADJ	YES		06-02-2008
(memory) and antenna and (electro-magnetic or electromagnetic)	PGPB, USPT	ADJ	YES		06-02-2008
(memory and antenna and (electro-magnetic or electromagnetic)) and power supply and (A.C or AC)	PGPB, USPT	ADJ	YES		06-02-2008
(memory and antenna and (electro-magnetic or electromagnetic) and power supply and (A.C or AC)) and (bitline\$ or bit line\$)	PGPB, USPT	ADJ	YES		06-02-2008
(memory and antenna and (electro-magnetic or electromagnetic) and power supply and (A.C or AC) and (bitline\$ or bit line\$)) and (wordline\$ or word line\$)	PGPB, USPT	ADJ	YES		06-02-2008
(memory and antenna and (electro-magnetic or electromagnetic) and power supply and (A.C or AC) and (bitline\$ or bit line\$) and (wordline\$ or word line\$)) and (phase-change or phase change)	PGPB, USPT	ADJ	YES		06-02-2008
		ADJ	YES		06-02-2008

(memory and antenna and (electro-magnetic or electromagnetic) and power supply and (A.C or AC) and (bitline\$ or bit line\$) and (wordline\$ or word line\$)) and phase\$	PGPB, USPT				
TFT or (thin-film or thin film)	USPT	ADJ	YES		09-02-2008
(TFT or (thin-film or thin film)) and 6097622	USPT	ADJ	YES		09-02-2008
(TFT or (thin-film or thin film)) and 6234902	USPT	ADJ	YES		09-02-2008
(TFT or (thin-film or thin film) and 6234902) and ferroelectric	USPT	ADJ	YES		09-02-2008
(TFT or (thin-film or thin film) and 6234902) and ferro\$	USPT	ADJ	YES		09-02-2008
ferro-electric or ferroelectric	USPT	ADJ	YES		09-02-2008
(ferro-electric or ferroelectric) and state	USPT	ADJ	YES		09-02-2008
(ferro-electric or ferroelectric and state) and (crystalline or crystalline)	USPT	ADJ	YES		09-02-2008
(ferro-electric or ferroelectric and state and (crystalline or crystalline)) and (phase-change or phase change)	USPT	ADJ	YES		09-02-2008
(ferro-electric or ferroelectric and state and (crystalline or crystalline) and (phase-change or phase change)) and memory	USPT	ADJ	YES		09-02-2008
(ferro-electric or ferroelectric and state and (crystalline or crystalline) and (phase-change or phase change) and memory) and amorphous	USPT	ADJ	YES		09-02-2008
(ferro-electric or ferroelectric and state and (crystalline or crystalline) and (phase-change or phase change) and memory) and amorphous adj2 state	USPT	ADJ	YES		09-02-2008
(ferro-electric or ferroelectric and state and (crystalline or crystalline) and (phase-change or phase change) and memory and amorphous adj2 state) and (crystalline or crystalline) adj2 state	USPT	ADJ	YES		09-02-2008
(ferro-electric or ferroelectric and state and (crystalline or crystalline) and (phase-change or phase change) and memory and amorphous adj2 state and (crystalline or crystalline) adj2 state) and card	USPT	ADJ	YES		09-02-2008
(ferro-electric or ferroelectric and state and (crystalline or crystalline) and (phase-change or phase change) and memory and amorphous adj2 state and (crystalline or crystalline) adj2 state) and (antena or antenna)	USPT	ADJ	YES		09-02-2008